Octal D-type flip-flop; positive edge-trigger; 3-state

FEATURES

- 3-state non-inverting outputs for bus oriented applications
- 8-bit positive edge-triggered register
- Common 3-state output enable input
- Independent register and 3-state buffer operation
- Output capability: bus driver
- I_{CC} category: MSI

GENERAL DESCRIPTION

The 74HC/HCT574 are high-speed Si-gate CMOS devices and are pin compatible with low power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT574 are octal D-type flip-flops featuring separate D-type inputs for each flip-flop and non-inverting 3-state outputs for bus oriented applications. A clock (CP) and an output enable (\overline{OE}) input are common to all flip-flops.

The 8 flip-flops will store the state of their individual D-inputs that meet the set-up and hold time requirements on the LOW-to-HIGH CP transition. When \overline{OE} is LOW, the contents of the 8 flip-flops are available at the outputs.

When \overline{OE} is HIGH, the outputs go to the high impedance OFF-state. Operation of the \overline{OE} input does not affect the state of the flip-flops.

The "574" is functionally identical to the "564", but has non-inverting outputs.

The "574" is functionally identical to the "374", but has a different pinning.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25 \text{ °C}$; $t_r = t_f = 6 \text{ ns}$

SYMBOL	PARAMETER	CONDITIONS	TYP		
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t _{PHL} / t _{PLH}	propagation delay CP to Q _n	C _L = 15 pF; V _{CC} = 5 V	14	15	ns
f _{max}	maximum clock frequency		123	76	MHz
CI	input capacitance		3.5	3.5	pF
C _{PD}	power dissipation capacitance per flip-flop	notes 1 and 2	22	25	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz

 $f_o = output frequency in MHz$

 $\Sigma (C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs}$

C_L = output load capacitance in pF

- V_{CC} = supply voltage in V
- 2. For HC the condition is $V_I = GND$ to V_{CC} For HCT the condition is $V_I = GND$ to $V_{CC} - 1.5$ V

ORDERING INFORMATION

See "74HC/HCT/HCU/HCMOS Logic Package Information".

74HC/HCT574

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DC CHARACTERISTICS FOR 74HC

For the DC characteristics see "74HC/HCT/HCU/HCMOS Logic Family Specifications".

Output capability: bus driver I_{CC} category: MSI

AC CHARACTERISTICS FOR 74HC

 $GND = 0 V; t_r = t_f = 6 ns; C_L = 50 pF$

SYMBOL	PARAMETER	T _{amb} (°C)								TEST CONDITIONS	
			74HC								
		+25			-40 to +85		-40 to +125			V _{CC} (V)	WAVEFORMS
		min.	typ.	max.	min.	max.	min.	max.		(•)	
t _{PHL} / t _{PLH}	propagation delay CP to Q _n		47 17 14	150 30 26		190 35 33		225 45 38	ns	2.0 4.5 6.0	Fig.6
t _{PZH} / t _{PZL}	3-state output enable time OE to Q _n		44 16 13	140 28 24		175 35 30		210 42 36	ns	2.0 4.5 6.0	Fig.7
t _{PHZ} / t _{PLZ}	3-state output disable time OE to Q _n		39 14 11	125 25 21		155 31 26		190 38 32	ns	2.0 4.5 6.0	Fig.7
t _{THL} / t _{TLH}	output transition time		14 5 4	60 12 10		75 15 13		90 18 15	ns	2.0 4.5 6.0	Fig.6
t _W	clock pulse width HIGH or LOW	80 16 14	14 5 4		100 20 17		120 24 20		ns	2.0 4.5 6.0	Fig.6
t _{su}	set-up time D _n to CP	60 12 10	6 2 2		75 15 13		90 18 15		ns	2.0 4.5 6.0	Fig.8
t _h	hold time D _n to CP	5 5 5	0 0 0		5 5 5		5 5 5		ns	2.0 4.5 6.0	Fig.8
f _{max}	maximum clock pulse frequency	6.0 30 35	37 112 133		4.8 24 28		4.0 20 24		MHz	2.0 4.5 6.0	Fig.6

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DC CHARACTERISTICS FOR 74HCT

For the DC characteristics see "74HC/HCT/HCU/HCMOS Logic Family Specifications".

Output capability: bus driver I_{CC} category: MSI

Note to HCT types

The value of additional quiescent supply current (ΔI_{CC}) for a unit load of 1 is given in the family specifications. To determine ΔI_{CC} per input, multiply this value by the unit load coefficient shown in the table below.

INPUT	UNIT LOAD COEFFICIENT
D _n	0.5
OE	1.25
CP	1.5

AC CHARACTERISTICS FOR 74HCT

GND = 0 V; $t_r = t_f = 6 ns$; $C_L = 50 pF$

SYMBOL	PARAMETER	T _{amb} (°C)								TEST CONDITIONS	
		74HCT									
		+25			-40 to +85		-40 to +125		UNIT	V _{CC} (V)	WAVEFORMS
		min.	typ.	max.	min.	max.	min.	max.		(-)	
t _{PHL} / t _{PLH}	propagation delay CP to Q _n		18	33		41		50	ns	4.5	Fig.6
t _{PZH} / t _{PZL}	3-state output enable time OE to Q _n		19	33		41		50	ns	4.5	Fig.7
t _{PHZ} / t _{PLZ}	3-state output disable time OE to Q _n		16	28		35		42	ns	4.5	Fig.7
t _{THL} / t _{TLH}	output transition time		5	12		15		18	ns	4.5	Fig.6
t _W	clock pulse width HIGH or LOW	16	7		20		24		ns	4.5	Fig.6
t _{su}	set-up time D _n to CP	12	3		15		18		ns	4.5	Fig.8
t _h	hold time D _n to CP	5	-1		5		5		ns	4.5	Fig.8
f _{max}	maximum clock pulse frequency	30	69		24		20		MHz	4.5	Fig.6